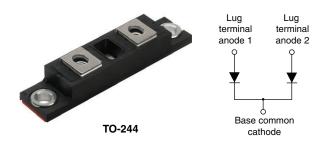
VS-HFA140NJ60CPbF

Vishay Semiconductors

HEXFRED[®] Ultrafast Soft Recovery Diode, 167 A



| PRIMARY CHARACTERISTICS | | | | |
|--------------------------------------|---------------------------|--|--|--|
| I _F (maximum) | 167 A | | | |
| V _R | 600 V | | | |
| I _{F(DC)} at T _C | 84 A at 100 °C | | | |
| Package | TO-244 | | | |
| Circuit configuration | Two diodes common cathode | | | |

FEATURES

- Very low Q_{rr} and t_{rr}
- UL approved file E222165
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Reduced RFI and EMI
- Reduced snubbing

DESCRIPTION / APPLICATIONS

HEXFRED[®] diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and dl_F/dt simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.

| ABSOLUTE MAXIMUM RATINGS | | | | | |
|--|-----------------------------------|--|-------------|-------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Cathode to anode voltage | V _R | | 600 | V | |
| Continuous forward current I _F | | $T_{C} = 25 \ ^{\circ}C$ | 167 | | |
| | | T _C = 100 °C | 84 | А | |
| Single pulse forward current | I _{FSM} | Limited by junction temperature | 400 | | |
| Non-repetitive avalanche energy | E _{AS} | L = 100 $\mu H,$ duty cycle limited by maximum $T_{\rm J}$ | 330 | μJ | |
| Maximum power dissipation | P _D | $T_{C} = 25 \ ^{\circ}C$ | 310 | W | |
| | | T _C = 100 °C | 132 | vv | |
| Operating junction and storage temperature range | T _J , T _{Stg} | | -55 to +150 | °C | |

| ELECTRICAL SPECIFICATIONS PER LEG ($T_J = 25 \text{ °C}$ unless otherwise specified) | | | | | | | |
|--|-----------------|---|------------|------|------|------|-------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS |
| Cathode to anode breakdown voltage | V _{BR} | I _R = 100 μA | | 600 | - | - | |
| | | I _F = 70 A | | - | 1.37 | 1.89 | V |
| Maximum forward voltage | V _{FM} | I _F = 140 A | See fig. 1 | - | 1.58 | 2.1 | |
| | | I _F = 70 A, T _J = 125 °C | | - | 1.29 | 1.54 | |
| Maximum reverse leakage current | I _{RM} | $T_J = 125 \text{ °C}, V_R = 480 \text{ V}$ | See fig. 2 | - | 1.2 | 4 | mA |
| Junction capacitance | CT | V _R = 200 V | See fig. 3 | - | 140 | 250 | pF |
| Series inductance | L _S | From top of terminal hole to mounting plane - 7.0 - n | | nH | | | |

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Document Number: 94051

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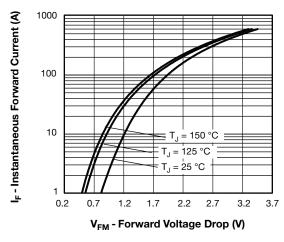
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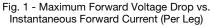
| DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25$ °C unless otherwise specified) | | | | | | | | |
|---|-------------------------|---|---|--|------|------|-------|----|
| PARAMETER | SYMBOL | TEST CONDITIONS | | MIN. | TYP. | MAX. | UNITS | |
| | | $I_F = 1.0 \text{ A}, \text{ d}I_F/\text{d}t =$ | \approx 200 A/µs, V _R = 30 V | - | 33 | - | ns | |
| Reverse recovery time (fig. 5) | t _{rr} | T _J = 25 °C | $l_{\rm F} = 70 {\rm A}$ | - | 80 | 120 | | |
| | | T _J = 125 °C | | - | 140 | 220 | | |
| Peak recovery current (fig. 6) | | $T_J = 25 \ ^\circ C$ | | - | 8.5 | 15 | | |
| Feak recovery current (lig. 6) | I _{RRM} | T _J = 125 °C | | - | 14 | 25 | A | |
| Bowerse receivery charge (fig. 7) | | | T _J = 25 °C | dI _F /dt = 200 A/µs V _R = 200 V | - | 340 | 900 | nC |
| Reverse recovery charge (fig. 7) | Q _{rr} | T _J = 125 °C | | - | 980 | 2300 | no | |
| Peak rate of recovery current (fig. 8) dI _{(rec)M} /dt | dl (dt | T _J = 25 °C | | - | 300 | - | A/µs | |
| | T _J = 125 °C | | _ | 220 | - | λγμs | | |

| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | |
|--|------------|-----------------------------------|----------|------|----------|---------------------|
| PARAMETER | | SYMBOL | MIN. | TYP. | MAX. | UNITS |
| Maximum junction and storage temperature range | | T _J , T _{Stg} | -55 | - | 150 | °C |
| Thermal resistance, junction to case | per leg | P | - | - | 0.38 | °C/W K/W |
| merma resistance, junction to case | per module | – R _{thJC} | - | - | 0.19 | |
| Typical thermal resistance, case to heatsink | | R _{thCS} | | 0.10 | - | |
| Weight | | | - | 68 | - | g |
| weight | | | - | 2.4 | - | oz. |
| Mounting torque ⁽¹⁾ | | | 30 (3.4) | - | 40 (4.6) | |
| Mounting torque center hole | | | 12 (1.4) | - | 18 (2.1) | lbf · in (N · m) |
| Terminal torque | | | 30 (3.4) | - | 40 (4.6) | (|
| Vertical pull | | | - | - | 80 | lbf∙in |
| 2" lever pull | | | - | - | 35 | חוייוטו |

Note

(1) Mounting surface must be smooth, flat, free or burrs or other protrusions. Apply a thin even film or thermal grease to mounting surface. Gradually tighten each mounting bolt in 5 - 10 lbf · in steps until desired or maximum torque limits are reached





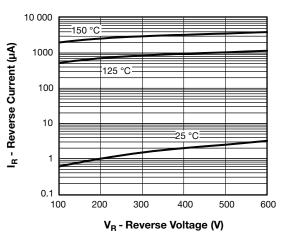


Fig. 2 - Typical Reverse Current vs. Reverse Voltage (Per Leg)

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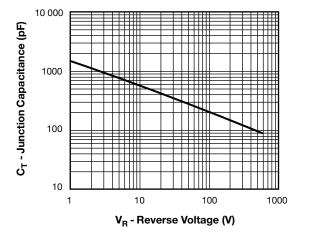


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

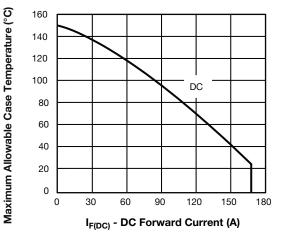


Fig. 4 - Maximum Allowable Case Temperature vs. DC Forward Current (Per Leg)

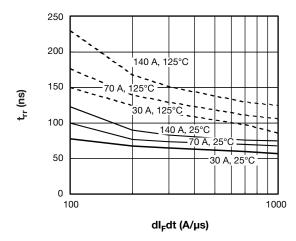


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt (Per Leg)

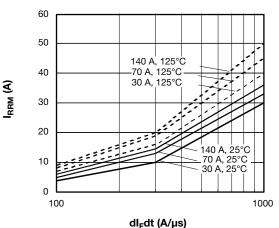


Fig. 6 - Typical Recovery Current vs. dl_F/dt (Per Leg)

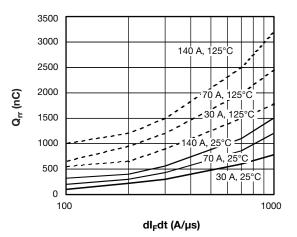


Fig. 7 - Typical Stored Charge vs. dl_F/dt (Per Leg)

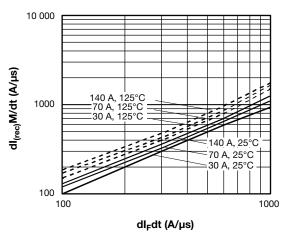


Fig. 8 - Typical dl_{(rec)M}/dt vs. dl_F/dt (Per Leg)

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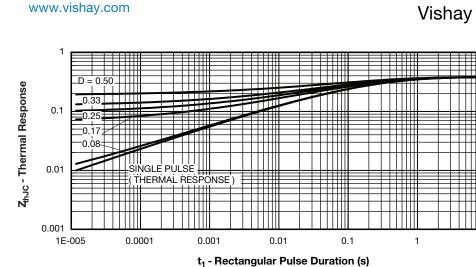


Fig. 9 - Maximum Thermal Impedance Z_{thJC} Characteristics

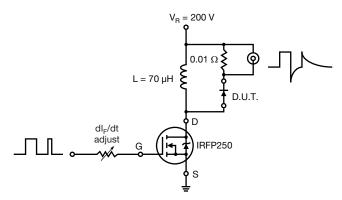


Fig. 10 - Reverse Recovery Parameter Test Circuit

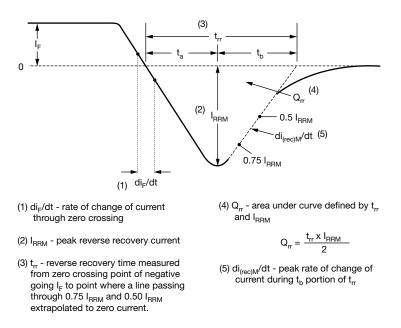


Fig. 11 - Reverse Recovery Waveform and Definitions

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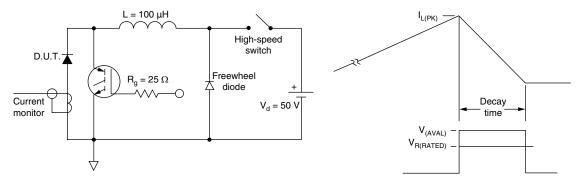
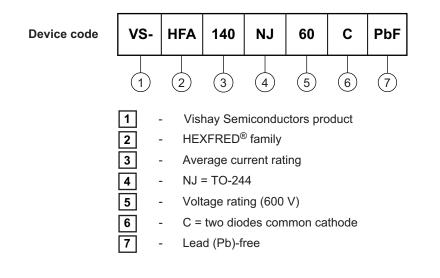


Fig. 12 - Avalanche Test Circuit and Waveforms

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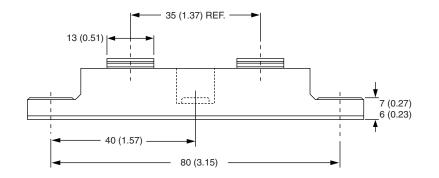


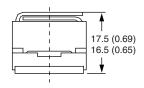


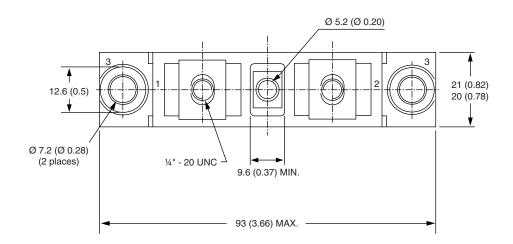
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TO-244

DIMENSIONS in millimeters (inches)









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